

SEMiX904GB126HDs



SEMiX® 4s

Trench IGBT Modules

SEMiX904GB126HDs

Features

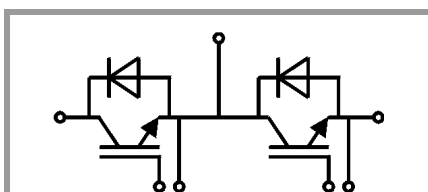
- Homogeneous Si
- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability
- UL recognised file no. E63532

Typical Applications*

- AC inverter drives
- UPS
- Electronic Welding

Remarks

- Case temperatur limited to $T_C=125^\circ\text{C}$ max.
- Not for new design



GB

Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
IGBT				
V _{CES}			1200	V
I _C	T _j = 150 °C	T _c = 25 °C	821	A
		T _c = 80 °C	572	A
I _{Cnom}			600	A
I _{CRM}	I _{CRM} = 2xI _{Cnom}		1200	A
V _{GES}			-20 ... 20	V
t _{psc}	V _{CC} = 600 V V _{GE} ≤ 20 V V _{CES} ≤ 1200 V	T _j = 125 °C	10	μs
T _j			-40 ... 150	°C
Inverse diode				
I _F	T _j = 150 °C	T _c = 25 °C	752	A
		T _c = 80 °C	516	A
I _{Fnom}			600	A
I _{FRM}	I _{FRM} = 2xI _{Fnom}		1200	A
I _{FSM}	t _p = 10 ms, sin 180°, T _j = 25 °C		3600	A
T _j			-40 ... 150	°C
Module				
I _{t(RMS)}	T _{terminal} = 80 °C		600	A
T _{stg}			-40 ... 125	°C
V _{isol}	AC sinus 50Hz, t = 1 min		4000	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT						
V _{CE(sat)}	I _C = 600 A	T _j = 25 °C		1.7	2.1	V
	V _{GE} = 15 V chipelevel	T _j = 125 °C		2.0	2.45	V
V _{CE0}		T _j = 25 °C		1	1.2	V
		T _j = 125 °C		0.9	1.1	V
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		1.2	1.5	mΩ
		T _j = 125 °C		1.8	2.3	mΩ
V _{GE(th)}	V _{GE} =V _{CE} , I _C = 24 mA		5	5.8	6.5	V
I _{CES}	V _{GE} = 0 V	T _j = 25 °C		0.12	0.36	mA
	V _{CE} = 1200 V	T _j = 125 °C				mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		43.1		nF
C _{oes}		f = 1 MHz		2.25		nF
C _{res}		f = 1 MHz		1.95		nF
Q _G	V _{GE} = - 8 V...+ 15 V			4800		nC
R _{Gint}	T _j = 25 °C			1.25		Ω
t _{d(on)}	V _{CC} = 600 V	T _j = 125 °C		440		ns
t _r	I _C = 600 A	T _j = 125 °C		85		ns
E _{on}	V _{GE} = ±15 V	T _j = 125 °C		60		mJ
t _{d(off)}	R _{G on} = 1.6 Ω	T _j = 125 °C		710		ns
t _f	R _{G off} = 1.6 Ω	T _j = 125 °C		130		ns
E _{off}		T _j = 125 °C		88		mJ
R _{th(j-c)}	per IGBT				0.05	K/W

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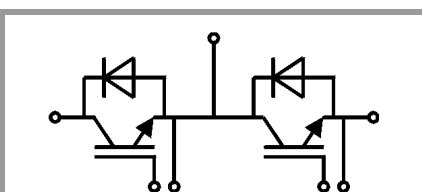
Typical Applications*

- AC inverter drives
- UPS
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Remarks

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Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse diode						
V _F = V _{EC}	I _F = 600 A	T _j = 25 °C		1.6	1.80	V
	V _{GE} = 0 V chip	T _j = 125 °C		1.6	1.8	V
V _{F0}		T _j = 25 °C	0.9	1	1.1	V
		T _j = 125 °C	0.7	0.8	0.9	V
r _F		T _j = 25 °C	0.8	1.0	1.2	mΩ
		T _j = 125 °C	1.2	1.3	1.5	mΩ
I _{RRM}	I _F = 600 A	T _j = 125 °C		625		A
Q _{rr}	di/dt _{off} = 8400 A/μs	T _j = 125 °C		165		μC
E _{rr}	V _{GE} = -15 V V _{CC} = 600 V	T _j = 125 °C		75		mJ
R _{th(j-c)}	per diode				0.081	K/W
Module						
L _{CE}				22		nH
R _{CC'+EE'}	res., terminal-chip	T _C = 25 °C		0.7		mΩ
		T _C = 125 °C		1		mΩ
R _{th(c-s)}	per module			0.03		K/W
M _s	to heat sink (M5)		3		5	Nm
M _t		to terminals (M6)	2.5		5	Nm
						Nm
w					400	g
Temperatur Sensor						
R ₁₀₀	T _C =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω
B _{100/125}	R(T)=R ₁₀₀ exp[B _{100/125} (1/T-1/T ₁₀₀)]; T[K];			3550 ±2%		K



GB

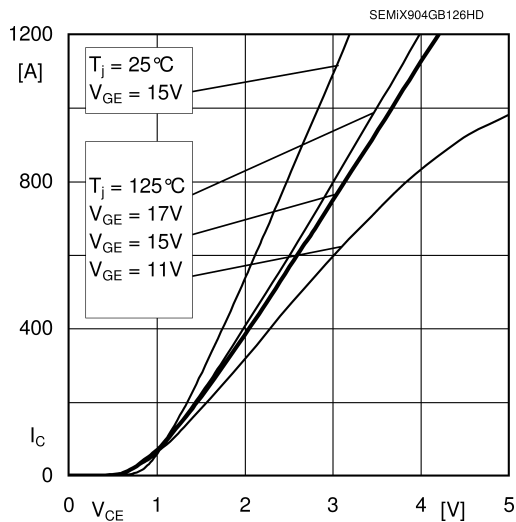


Fig. 1: Typ. output characteristic, inclusive $R_{CC'} + E_{E'}$

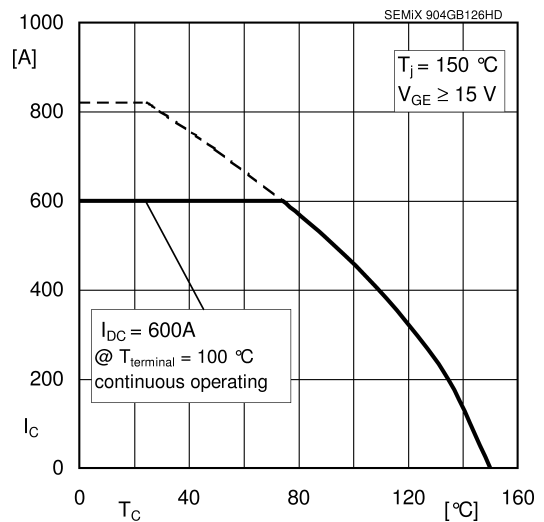


Fig. 2: Rated current vs. temperature $I_C = f(T_C)$

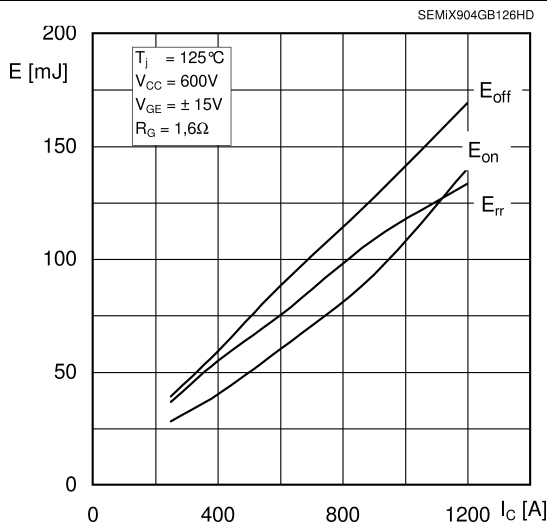


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

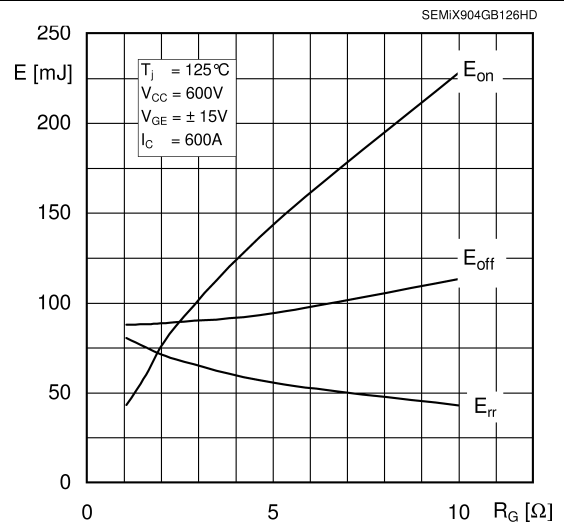


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

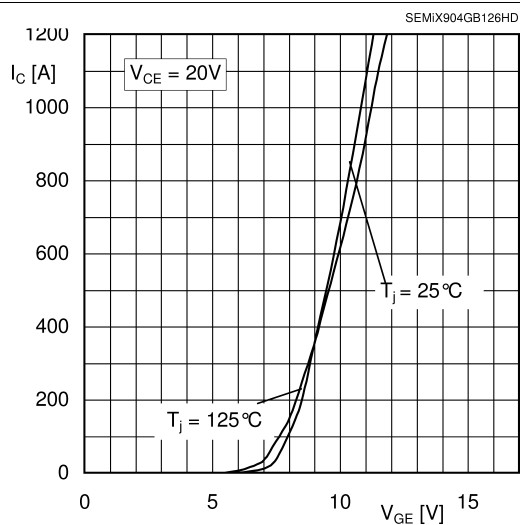


Fig. 5: Typ. transfer characteristic

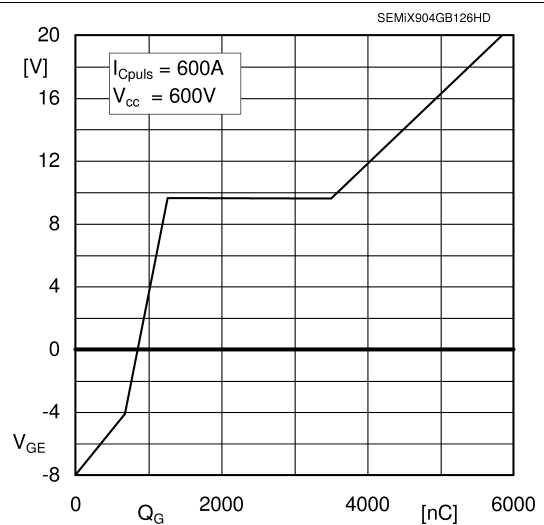
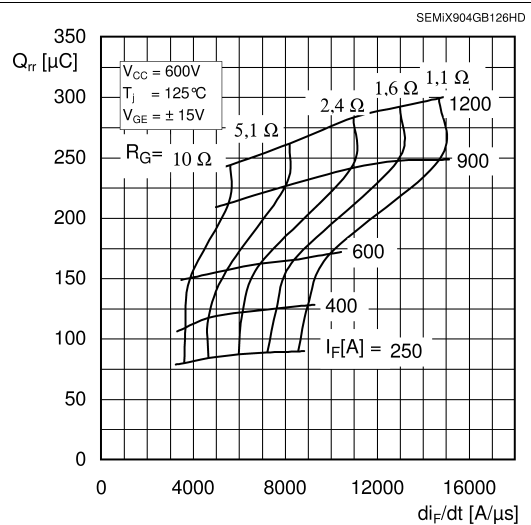
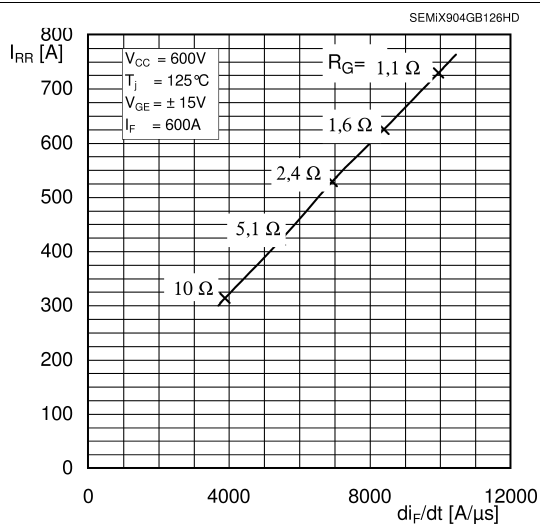
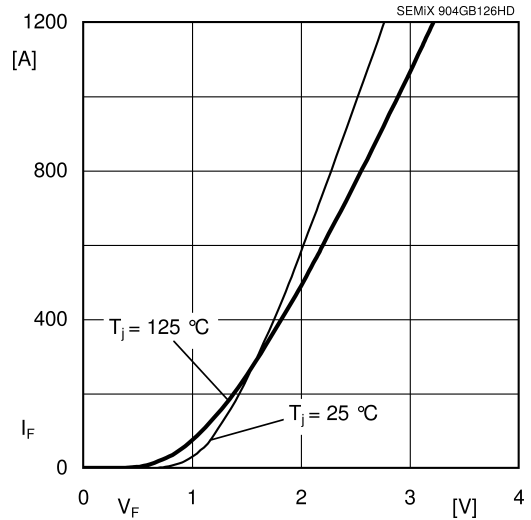
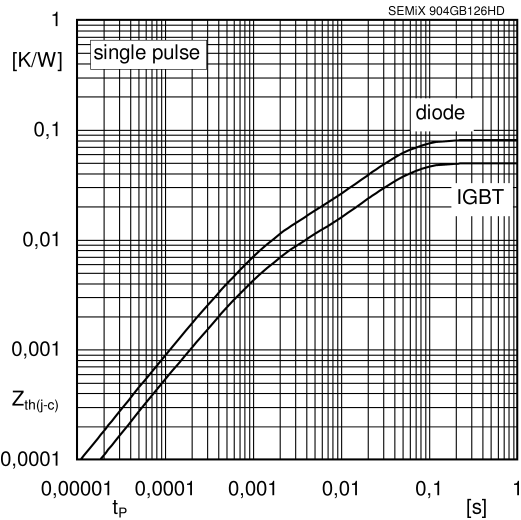
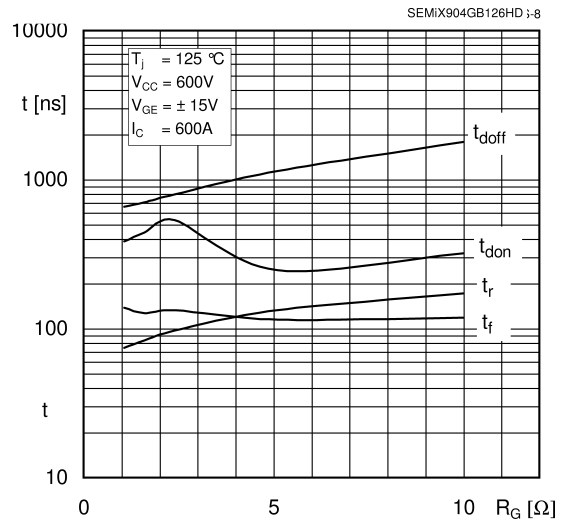
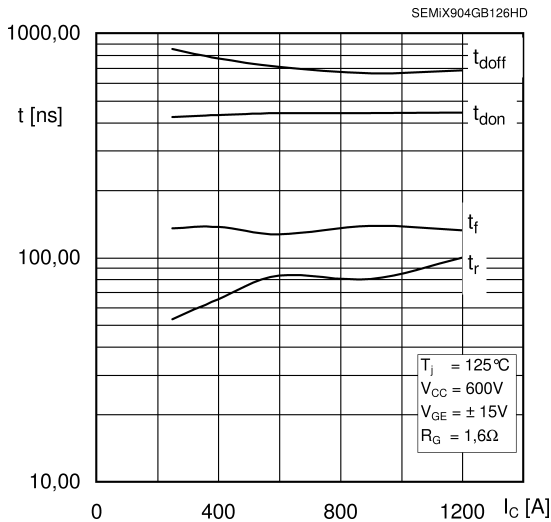
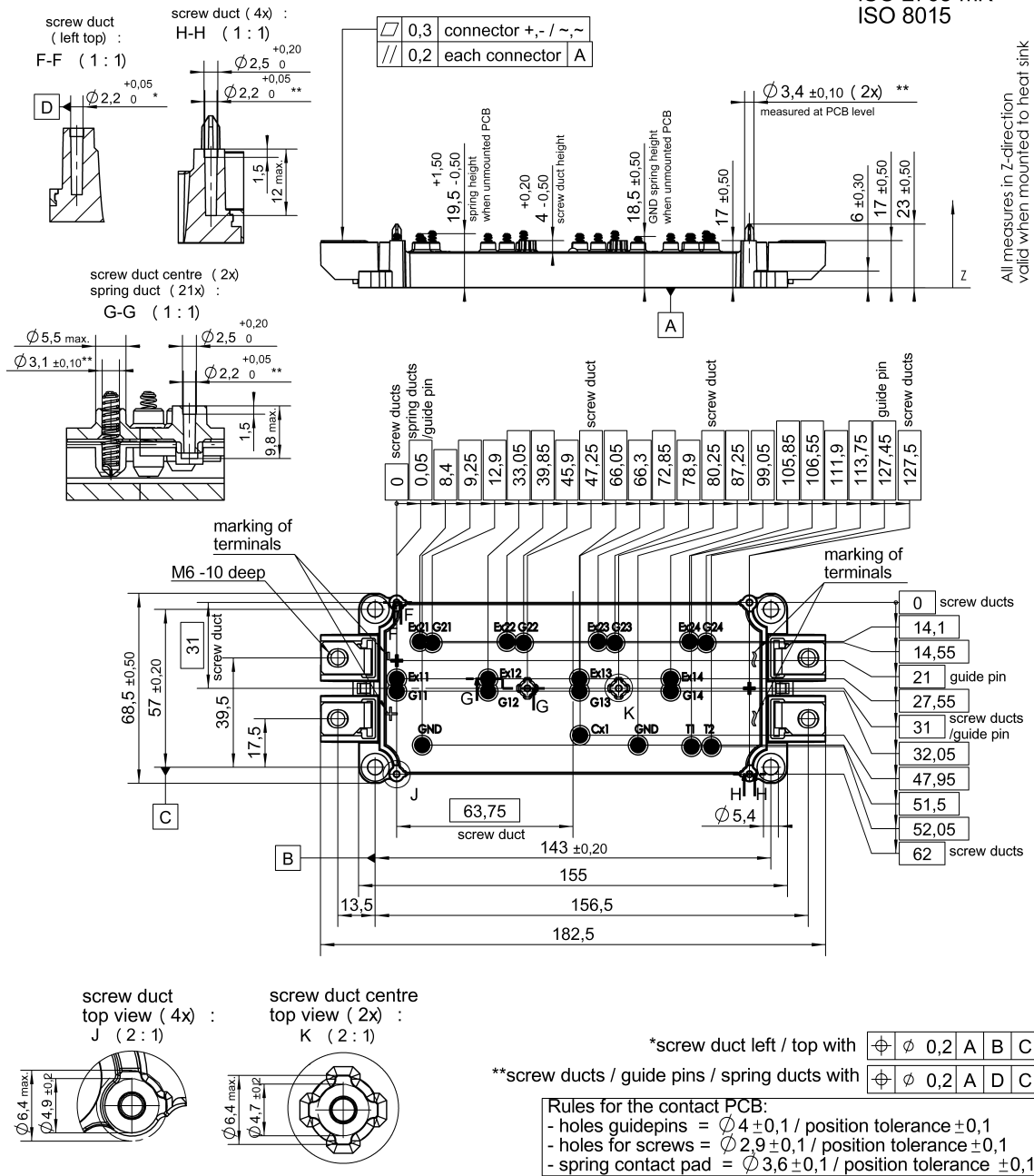


Fig. 6: Typ. gate charge characteristic

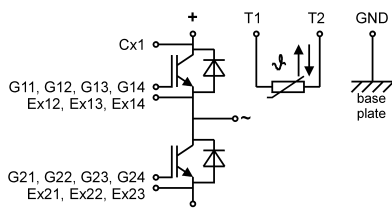


Case: SEMiX 4s

general tolerance:
ISO 2768-mK
ISO 8015



SEMIX 4s



spring configuration

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.